
**FEATURES**

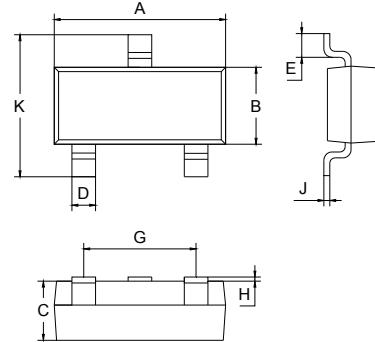
- Low noise and high gain.  
NF=1.1dB TYP., G<sub>a</sub>=11dB TYP.  
@V<sub>CE</sub>=10V, I<sub>c</sub>=7mA, f=1.0GHz
- High power gain. MAG=13dB TYP.  
@V<sub>CE</sub>=10V, I<sub>c</sub>=20mA, f=1.0GHz.

**APPLICATIONS**

- Designed for low noise amplifier at VHF,UHF and CATV band.

**ORDERING INFORMATION**

Type No.	Marking	Package Code
2SC3356	R23/R24/R25	SOT-23



SOT-23		
Dim	Min	Max
A	2.70	3.10
B	1.10	1.50
C	1.0 Typical	
D	0.4 Typical	
E	0.35	0.48
G	1.80	2.00
H	0.02	0.1
J	0.1 Typical	
K	2.20	2.60

All Dimensions in mm

**SOT-23**
**MAXIMUM RATING @ Ta=25°C unless otherwise specified**

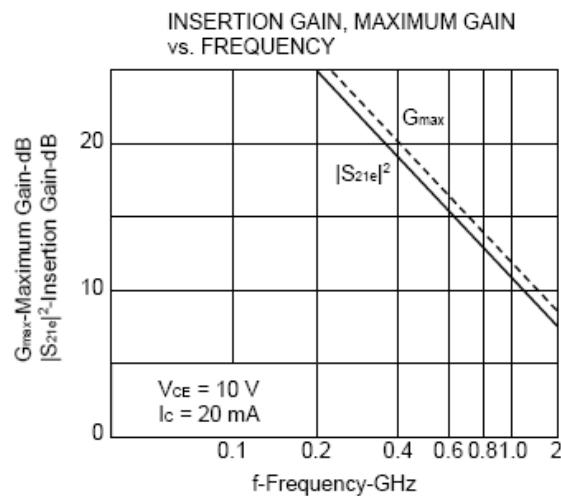
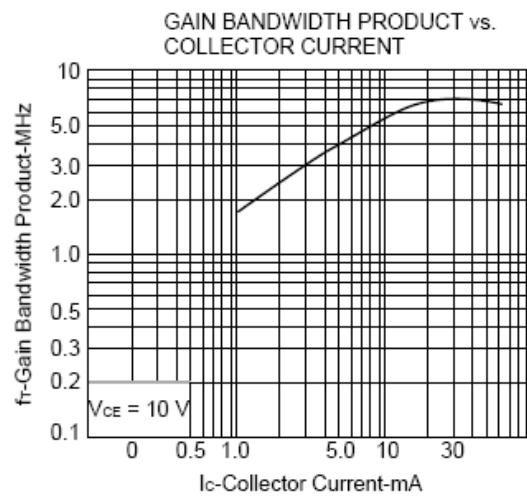
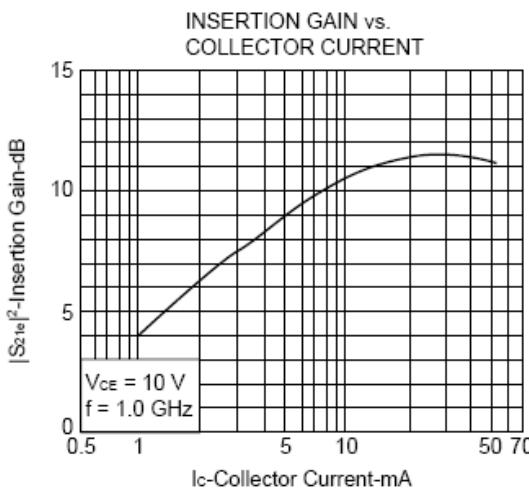
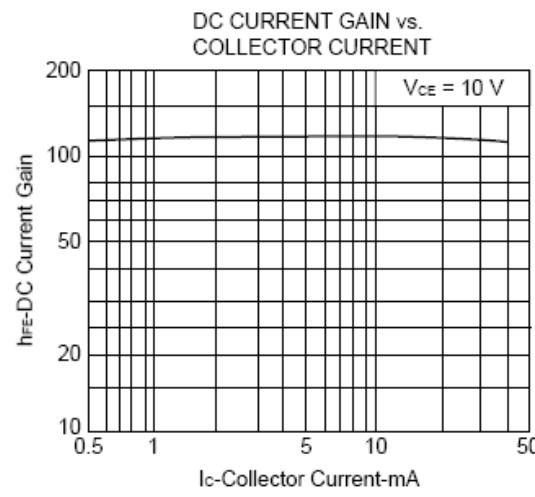
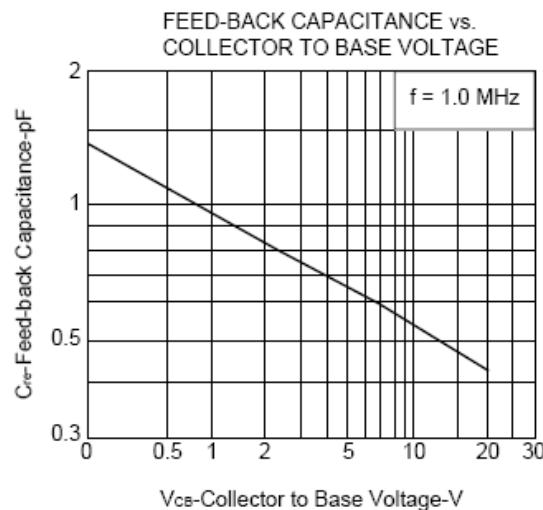
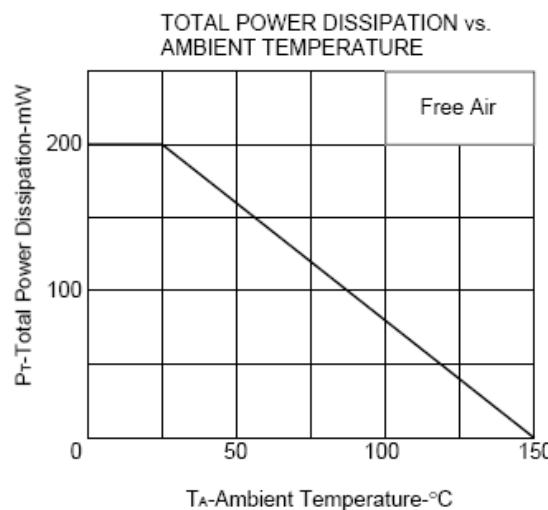
Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	20	V
V <sub>CEO</sub>	Collector-Emitter Voltage	12	V
V <sub>EBO</sub>	Emitter-Base Voltage	3	V
I <sub>C</sub>	Collector Current -Continuous	100	mA
P <sub>C</sub>	Collector Dissipation	200	mW
T <sub>j</sub> , T <sub>stg</sub>	Junction and Storage Temperature	-65 to +150	°C

**ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified**

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> =10µA, I <sub>E</sub> =0	20			V
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> =1mA, I <sub>B</sub> =0	12			V
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =10µA, I <sub>C</sub> =0	3			V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> =10V, I <sub>E</sub> =0			1	µA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> =1V, I <sub>C</sub> =0			1	µA
DC current gain	h <sub>FE</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> =20mA	50	120	300	
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> = 20mA		7		GHz
Insertion power gain	S <sub>21e</sub>   <sup>2</sup>	V <sub>CE</sub> =10V, I <sub>C</sub> = 20mA , f=1GHz		11.5		dB
Feed-back capacitance	C <sub>re</sub>	V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1MHz		0.55	1.0	pF
Noise Figure	NF	V <sub>CE</sub> =10V, I <sub>C</sub> =7mA, f=1GHz		1.1	2.0	dB

**CLASSIFICATION OF h<sub>FE</sub>**

Rank	Q	R	S
Range	50-100	80-160	125-250
Marking	R23	R24	R25

**TYPICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified**


Device	Package	Shipping
2SC3356	SOT-23	3000/Tape&Reel

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